

# Linear Voltage Regulator – 79L05AC

#### Negative Fixed 5V Voltage Regulator in bare die form

## Description

79L05AC 5V fixed 3-terminal negative voltage regulator delivers up to 100mA output current & is equipped with internal limiting + thermal shutdown features for overload immunity. Implementing this device at point-of-source removes the complexity of single point regulation methods + reduces noise. In replacement of a Zener diode/resistor combination, the device improves output impedance by x2 order of magnitude & delivers lower bias current with lower noise. The 79L05AC can be used with power-pass elements to make high-current voltage regulators.

# **Ordering Information**

The following part suffixes apply:

- No suffix MIL-STD-883 /2010B Visual Inspection
- "H" MIL-STD-883 /2010B Visual Inspection + MIL-PRF-38534 Class H LAT
- "K" MIL-STD-883 /2010A Visual Inspection (Space) + MIL-PRF-38534 Class K LAT

LAT = Lot Acceptance Test.

For further information on LAT process flows see below.

www.siliconsupplies.com\quality\bare-die-lot-qualification

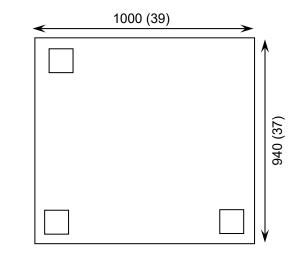
# Supply Formats:

- Default Die in Waffle Pack (400 per tray capacity)
- Sawn Wafer on Tape On request
- Unsawn Wafer On request
- With Ti/Ni/Ag Back Metal On request
- In Metal or Ceramic package On request

### Features:

- ±4% V<sub>OUT</sub> tolerance
- 100mA Output Current
- Internal thermal overload protection
- Internal short circuit current limit
- Full Military Temperature Range
- Positive Voltage complement is 78L05AC

# Die Dimensions in µm (mils)



# **Mechanical Specification**

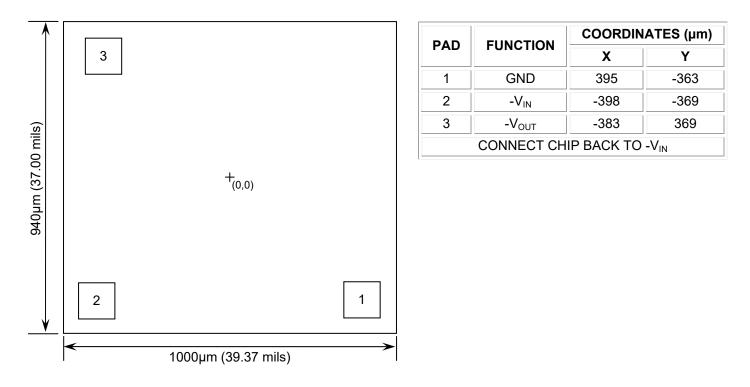
Die Size (Unsawn)	1000 x 940 39 x 37	µm mils	
Minimum Bond Pad Size	110 x 110 4.33 x 4.33	µm mils	
Die Thickness	280 (±20) 11 (±0.8)	µm mils	
Top Metal Composition	Al-Si-Cu 3µm		
Back Metal Composition	N/A – Bare Si		



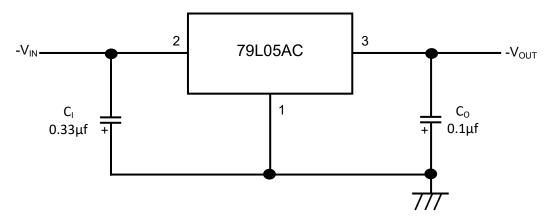


#### Rev 1.0 01/05/25

## Pad Layout and Functions



## **Typical Application**



 $C_l$  is required if the regulator is located an appreciable distance from power supply filter.  $C_o$  is not required for stability; however it does improve transient response. For optimum stability and transient response locate  $C_l C_o$  as close as possible to the regulator.





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## Absolute Maximum Ratings

PARAMETER	SYMBOL VALUE		UNIT
Input Voltage	V <sub>IN</sub>	-30	V
Power Dissipation <sup>1</sup>	PD	625	mW
Operating Temperature Range	-	-55 to 125	°C
Maximum Junction Temperature	TJ	150	°C
Storage Temperature	T <sub>STG</sub>	-65 to 150	°C

## **Recommended Operating Conditions**

PARAMETER	SYMBOL	MIN	MAX	UNIT
Input Voltage	V <sub>IN</sub>	-7	-20	V
Output Current	I <sub>OUT</sub>	-	100	mA
Operating Temperature Range	TJ	-55	125	°C

## DC Electrical Characteristics V<sub>I</sub> = -10V, I<sub>OUT</sub>=40mA,C<sub>I</sub>=0.33µF, C<sub>0</sub>=0.1µf, 0°C<T<sub>J</sub><+125°C(unless noted otherwise)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Output Voltage V <sub>OUT</sub>		$T_{\rm J} = 25^{\circ}C, I_{\rm O} = 40 {\rm mA}$	-4.80	-5.00	-5.20	V
	V <sub>OUT</sub>	$1\text{mA} \le I_{\text{OUT}} \le 40\text{mA}, -7\text{V} \ge \text{V}_{\text{IN}} \ge -20\text{V}$	-4.75	-5.00	-5.25	
	$1\text{mA} \le I_{\text{OUT}} \le 70\text{mA}, V_{\text{IN}} = -10\text{V}$	-4.75	-5.00	-5.25		
Line Regulation $\Delta V_{OUT}$	$-7V \ge V_{IN} \ge -20V, T_J = 25^{\circ}C, I_O = 40mA$	-	32	150	mV	
	$-8V \ge V_{IN} \ge -20V, T_J = 25^{\circ}C, I_O = 40mA$	-	26	100		
Load Regulation ΔV <sub>OUT</sub>	۸\/	$1\text{mA} \le I_{\text{OUT}} \le 100\text{mA}, T_{\text{J}} = 25^{\circ}\text{C}$	-	15	60	mv
	ΔVOUT	$1\text{mA} \le I_{\text{OUT}} \le 40\text{mA}, T_{\text{J}} = 25^{\circ}\text{C}$	-	8	30	
Input Bias Current		$T_{J} = 25^{\circ}C$	-	3.5	6.0	mA
	IB	T <sub>J</sub> = 125°C	-	-	5.5	
Input Bias Current	t Bias Current	$-8V \ge V_{IN} \ge -20V$	-	-	1.5	mA
Change ΔI <sub>B</sub>	$1mA \le I_{OUT} \le 40mA$	-	-	0.1	ША	
Output Noise Voltage	e <sub>N</sub>	10Hz ≤ f ≤ 100KHz, T <sub>J</sub> = 25°C	-	40	-	$\mu V_{RMS}$
Ripple Rejection	RR	f = 120Hz,-8V ≥ V <sub>IN</sub> ≥ 18V,T <sub>J</sub> = 25°C	41	71	-	dB
Dropout Voltage	VD	V <sub>IN</sub> -V <sub>OUT</sub>	-	1.7	-	V

**1.** Value measured in TO-92 package applicable only for DC power dissipation permitted by absolute maximum ratings. Results in die form are dependent on die attach and assembly method.





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